EL979949448

Inventor:

Cem Basc ri

Capacitor Constructions Comprising P rovskit -Typ Dielectric

Materials

gnee:

Micron Technology, Inc.

Serial No.: 10/086,942

Filed:

March 1, 2002 [RCE Filed Herewith]

INFORMATION DISCLOSURE STATEMENT

PURSUANT TO 37 C.F.R. §§ 1.56, 1.97 AND 1.98

In compliance with 37 C.F.R. §§ 1.56, 1.97 and 1.98, the Examiner's attention is directed to the references listed on the attached Form PTO-1449 and copies of which are attached. No admission is made regarding whether all the submitted references are prior art.

Citation of these references is respectfully requested.

12/29/03

Attornev:

David G. Latwesen, Ph.D.

Respectfully submitted,

Reg. No. 38,533

Wells, St. John P.S.

Form PTO-1449 U.S. DEPARTMENT OF COMMERCE ATTY. DOCKET NO. MI22-1951 SERIAL NO. 10/086,942 PATENT AND TRADEMARK OFFICE IST OF ART CITED BY APPLICANT APPLICANT (Use several sheets if necessary) Cem Basceri FILING DATE **GROUP** 3/1/02 [RCE Filed Herewith] 2813 U.S. PATENT DOCUMENTS *Examiner Date Document Class Subclass Filing Date Name Initial Number If Appropriate AA 6,236,076 B1 05/01 Arita et al. AB 6,285,051 B1 09/01 Ueda et al. AC 5,635,741 06/97 Tsu et al. AD 6,422,281 B1 07/02 Ensign Jr. et al. ΑE 6,527,028 B2 03/03 Miller ΑF 6,602,376 B1 08/03 Bradshaw AG ΑH ΑI ΑJ ΑK AL FOREIGN PATENT DOCUMENTS Document Date Class Country Subclass Translation Number Yes No AM AN ΑO ΑP AQ OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, Etc.) AR AS

EXAMINER DATE CONSIDERED

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

ΑT